Design of a Simple CS Amplifier

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I. CS Amplifier

The desired specs are as follows:

- $|A_v| > 40$ at $V_{DS} = V_{DD}/2 = 0.9V$
- Output swing: $400mV$
- Unity-gain frequency: $f_u = 100MHz$, $C_L = 5pF$
- $V^* = 200mV$

A. Selecting I_D

The transconductance can be obtained from:

$$g_m = 2\pi f_u C_L$$

this gives us

$$g_m = 3.14\ mS$$

The current can be obtained from:

$$V^* = 2 \cdot \left(\frac{g_m}{I_D}\right)^{-1}$$

and a V^* of $200\ mV$ corresponds to a g_m/I_D of 10.

Thus,

$$I_D = 314\ \mu A$$

B. Choosing the length

To find the appropiate length, I did a DC sweep on VGS and checked if the intrinsic gain at V^* is > 40.

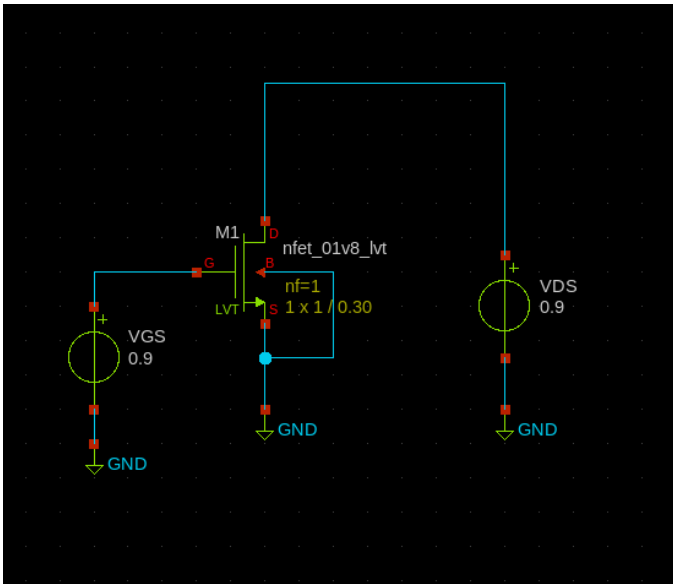

Fig. 1. Schematic diagram

At the minimum length, the intrinsic gain is lower than what is desired. We select $L = 0.30\mu m$ since it satisfies the specifications. $L = 0.25\mu m$ also meets the specifications, however, for a greater swing, the larger length is selected.

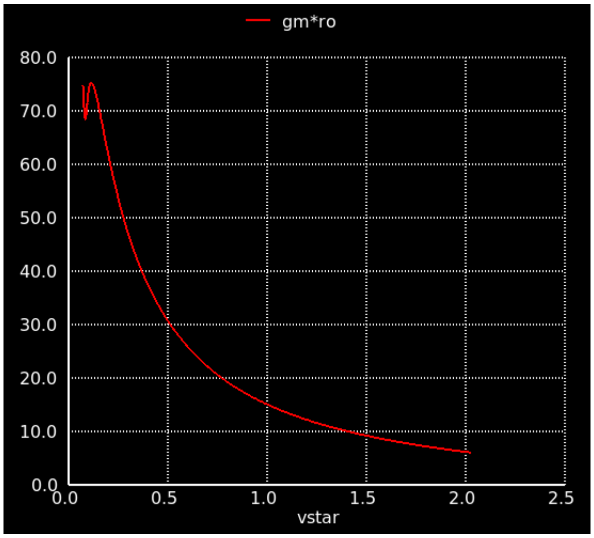

Fig. 2. Intrinsic gain

The V^* vs I_D plot for a transistor with $W = 1\mu m$, $L = 0.30\mu m$ is shown below.

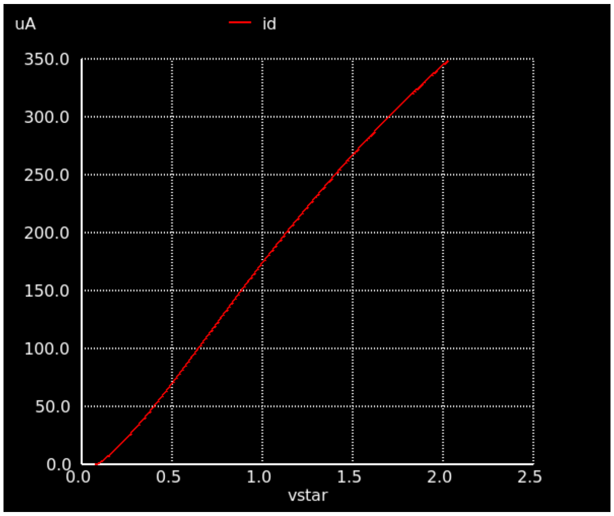

Fig. 3. I_D vs V^*, $W = 1\mu m$

C. Scaling the width

A python script is used to calculate the scale factor k_W to achieve the required I_D. The width is scaled using k_W. Multiplying the width by k_W scales I_D by approximately the same factor. For this activity, $k_W = 21$. To check, a MEAS directive is used. The required current is $I_D = 314\mu A$, what we got is $I_D = 345\mu A$, which is quite close.

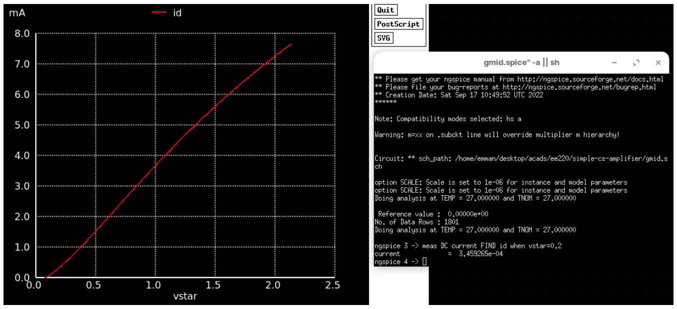

Fig. 4. I_D vs V^*, $W = 21\mu m$

D. Output and input swing

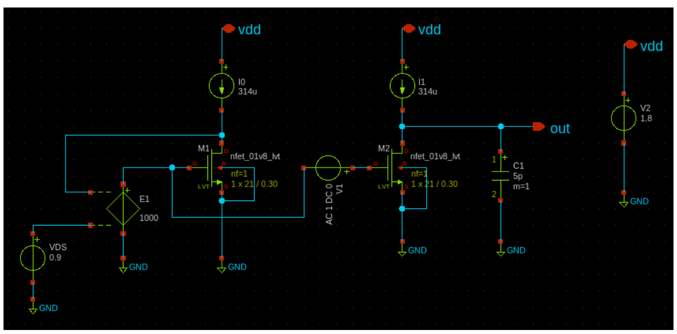

Fig. 5. Schematic

To get the input and output swing, we use the schematic in Fig. 5. Since V_{GS} is a function of V_{DS}, we can plot a_o vs V_{DS} to get the maximum output swing and a_o vs V_{GS} to get the corresponding input swing.

1) Output Swing: at $V_{DS} \approx 0.52$, $a_o \geq 40$.

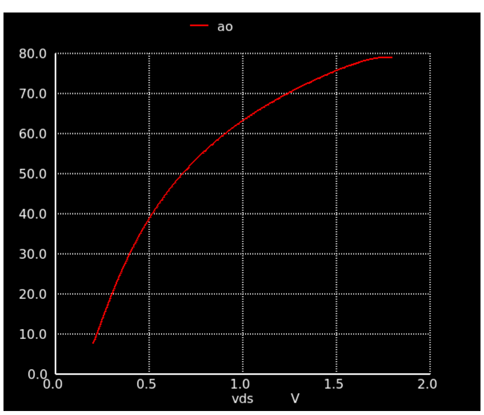

Fig. 6. a_o vs V_{DS}

2) Input Swing: at $V_{GS} \approx 0.70$, $a_o \geq 40$.

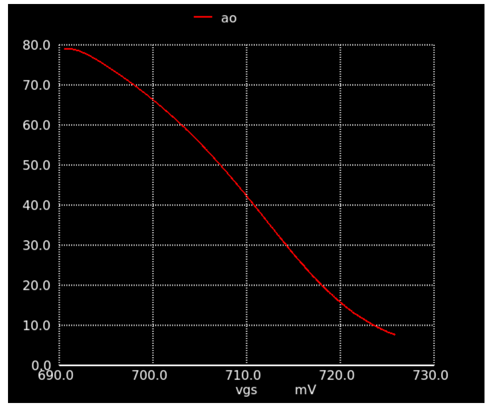

Fig. 7. a_o vs V_{GS}

Thus, the maximum symmetric output voltage is $0.52 \leq V_{DS} \leq 1.48$ for a total swing of $0.96V$. The corresponding input is $0.69 \leq V_{GS} \leq 0.71$ with a $20mV$ swing.

E. AC analysis

Using Fig. 5, an AC sweep from $1Hz$ to $1GHz$ is used to obtain Fig. 8. Using a MEAS directive, $f_u = 104MHz$ which is close to our desired f_u. At low frequencies, the gain is $\approx 35dB$ which is ≈ 60 V/V

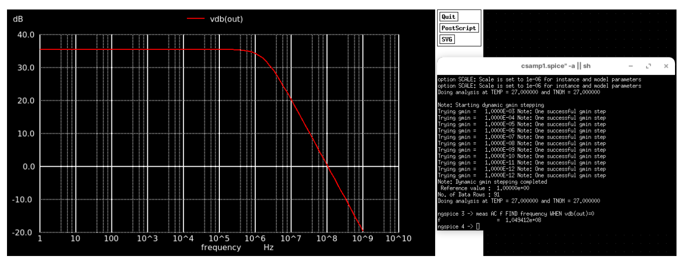

Fig. 8. Magnitude response

F. Discussions

These are my expected results. Since some values are estimated, there are slight deviations with the desired specifications.

II. CS Amplifier with High f_t

To get a high f_t, we need a high I_D and small L. Decreasing L increases f_t if I_D is kept constant. However, since there are no constraints on area and how high I_D could be, the limit would be related to the maximum W that can be used on the PDK.

A. Selecting the width

For this PDK, the highest width that can be used is $W = 99.9\mu m$. We use this value to get the maximum I_D.

B. Choosing V^* and L